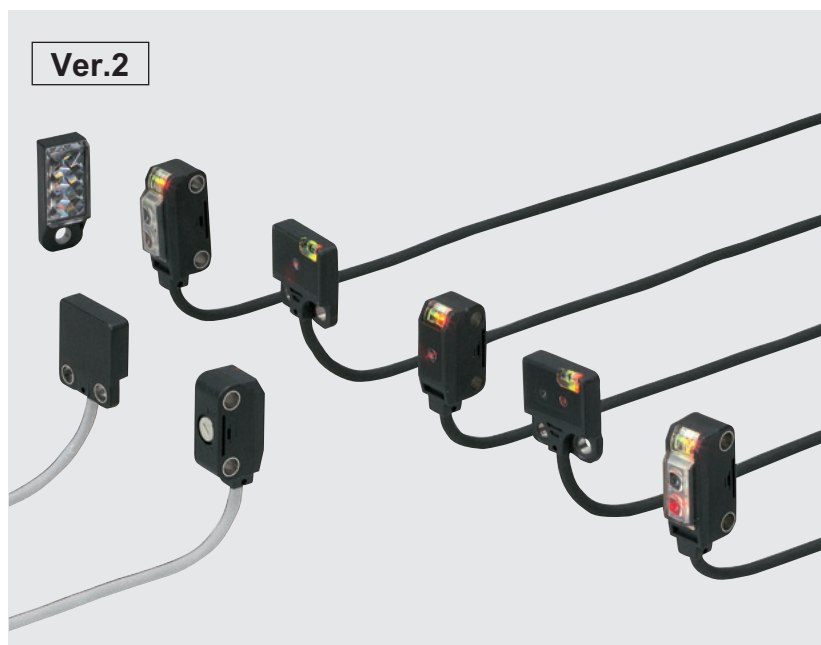
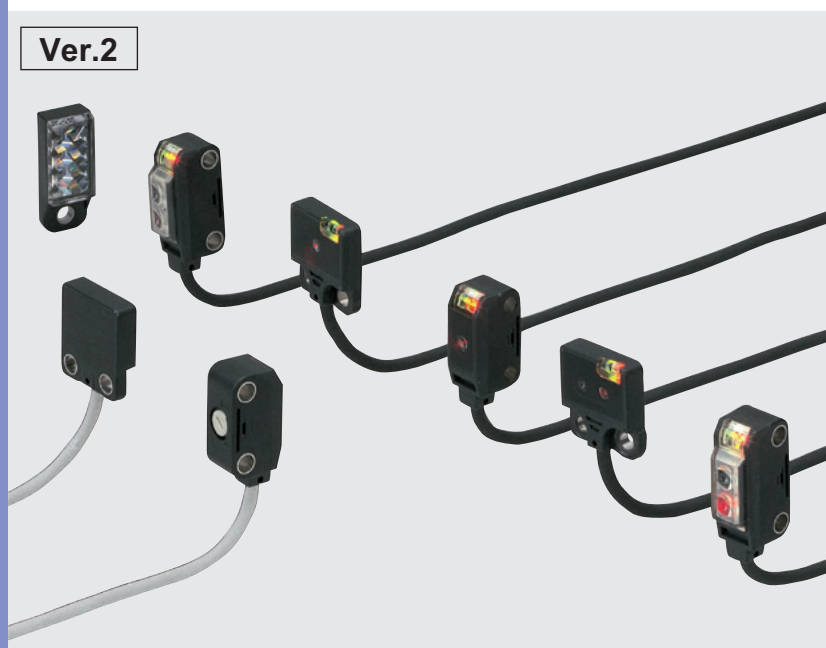


Amplifier Built-in

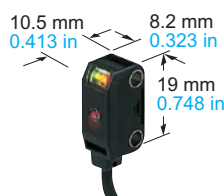
Ultra-compact Photoelectric Sensor

EX-20 SERIES Ver.2



EX-20 SERIES Ver.2**Miniature-sized and still mountable with M3 screws****Miniaturization by using single chip optical IC**

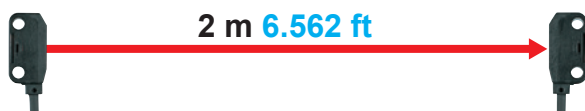
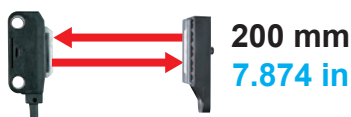
The beam-receiving photodiode and the A/D conversion circuit have been fabricated on a single chip optical IC (full custom). Hence, in spite of its miniature size, it has a performance and reliability which is equal to or better than the conventional product.

**Incorporates a sensitivity adjuster even in this size**

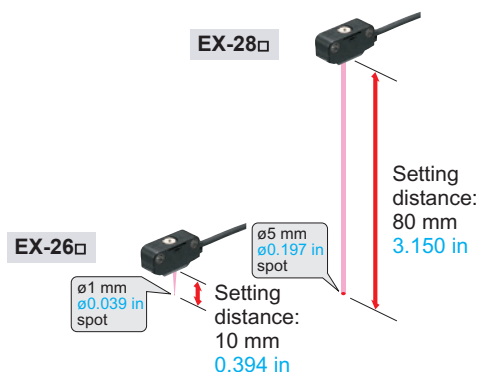
The sensor incorporates a sensitivity adjuster in spite of its miniature size. It is convenient when you need fine adjustment. Further, the receiver of the thru-beam, side sensing type sensor incorporates an operation mode switch which can change the output operation.

**BASIC PERFORMANCE****Long sensing range**

The EX-20 series achieves long distance sensing [thru-beam type: 2 m **6.562 ft**, retroreflective type: 200 mm **7.874 in** (when using the attached reflector), diffuse reflective type: 160 mm **6.299 in**], despite its miniature size. Hence, it is usable even on a wide conveyor.

Thru-beam type**Retroreflective type****Diffuse reflective type****Clear beam spot using red LED dot light source**

The emission area of a dot light source is smaller than that of a conventional LED flat light source, and it is possible to design a high power, narrow beam. Since a red LED dot light source is used, the red beam spot is clear even at a far place, so that alignment and confirmation of sensing position is easy. Further, since the thru-beam type, too, incorporates a visible narrow beam, it can also reliably detect small parts, such as, chip components, lead frames, etc.



FUNCTIONS**Bright 2-color indicator**

A bright 2-color indicator has been incorporated in all types.
(Orange LED: Operation indicator, Green LED: Stability indicator)

VARIETIES**Two types for suitable mounting**

Two types, side sensing type and front sensing type sensors are available. Select depending on the place of mounting.

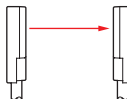
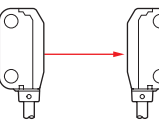
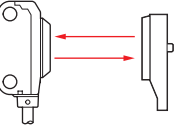
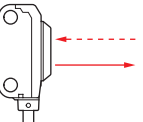
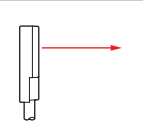
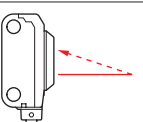
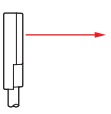
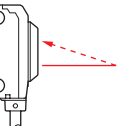
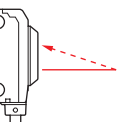
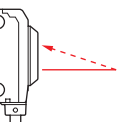
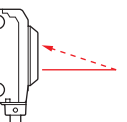
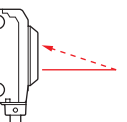
Side sensing type

(With sensitivity adjuster)

Front sensing type

(Without sensitivity adjuster)

ORDER GUIDE

Type	Appearance	Sensing range	Model No. (Note 3)	Output	Output operation
Thru-beam	Front sensing	 1 m 3.281 ft	EX-21A	NPN open-collector transistor	Light-ON
			EX-21A-PN	PNP open-collector transistor	
	Side sensing	 2 m 6.562 ft	EX-21B	NPN open-collector transistor	Dark-ON
			EX-21B-PN	PNP open-collector transistor	
Retroreflective	Side sensing	 30 to 200 mm 1.181 to 7.874 in (Note 1)	EX-23	NPN open-collector transistor	Switchable either Light-ON or Dark-ON
			EX-23-PN	PNP open-collector transistor	
	Side sensing	 5 to 160 mm 0.197 to 6.299 in (Note 2)	EX-22A	NPN open-collector transistor	Light-ON
			EX-22A-PN	PNP open-collector transistor	
Diffuse reflective	Side sensing	 5 to 160 mm 0.197 to 6.299 in (Note 2)	EX-22B	NPN open-collector transistor	Dark-ON
			EX-22B-PN	PNP open-collector transistor	
	Side sensing	 5 to 160 mm 0.197 to 6.299 in (Note 2)	EX-22A	NPN open-collector transistor	Light-ON
			EX-22A-PN	PNP open-collector transistor	
Convergent reflective	Diffused beam type	 2 to 25 mm 0.079 to 0.984 in (Convergent point: 10 mm 0.394 in)	EX-24A	NPN open-collector transistor	Light-ON
			EX-24A-PN	PNP open-collector transistor	
	Small spot beam type	 6 to 14 mm 0.236 to 0.551 in (Convergent point: 10 mm 0.394 in)	EX-24B	NPN open-collector transistor	Dark-ON
			EX-24B-PN	PNP open-collector transistor	
Narrow-view reflective	Long distance spot beam type	 45 to 115 mm 1.772 to 4.528 in	EX-26A	NPN open-collector transistor	Light-ON
			EX-26A-PN	PNP open-collector transistor	
	Long distance spot beam type	 45 to 115 mm 1.772 to 4.528 in	EX-26B	NPN open-collector transistor	Dark-ON
			EX-26B-PN	PNP open-collector transistor	
Narrow-view reflective	Long distance spot beam type	 45 to 115 mm 1.772 to 4.528 in	EX-28A	NPN open-collector transistor	Light-ON
			EX-28A-PN	PNP open-collector transistor	
	Long distance spot beam type	 45 to 115 mm 1.772 to 4.528 in	EX-28B	NPN open-collector transistor	Dark-ON
			EX-28B-PN	PNP open-collector transistor	

NOTE: Mounting bracket is not supplied with the sensor. Please select from the range of optional sensor mounting brackets (four types) or universal sensor mounting bracket. (Refer to p.6)

Notes: 1) The sensing range of the retroreflective type sensor is specified for the **RF-200** reflector.

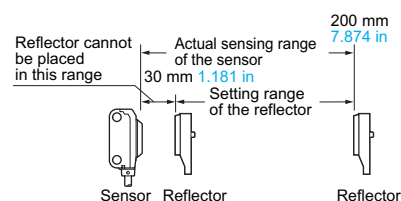
Further, the sensing range is the possible setting range for the reflector.

The sensor can detect an object less than 30 mm 1.181 in away.

However, if the reflector is set 100 mm 3.937 in or less away, the sensing object should be opaque.

2) In case of using this product at a sensing range of 50 mm 1.969 in or less, take care that the sensitivity adjustment range becomes extremely narrow.

3) The model No. with "P" shown on the label affixed to the thru-beam type sensor is the emitter, "D" shown on the label is the receiver.



SPECIFICATIONS

Item	Model No. (Note 2)	Type	Thru-beam		Retroreflective	Diffuse reflective	Convergent reflective		Narrow-view reflective
			Front sensing	Side sensing	Side sensing	Side sensing	Front sensing	Side sensing	Side sensing
			Light-ON EX-21A(-PN)	EX-23(-PN) (Note 3)	EX-29A(-PN)	EX-22A(-PN)	EX-24A(-PN)	EX-26A(-PN)	EX-28A(-PN)
Dark-ON EX-21B(-PN)		EX-29B(-PN)	EX-22B(-PN)	EX-24B(-PN)	EX-26B(-PN)	EX-28B(-PN)			
Applicable regulations and certifications			CE Marking (EMC Directive, RoHS Directive), UKCA Marking (EMC Regulations, RoHS Regulations), UL Recognition certification						
Sensing range			1 m 3.281 ft	2 m 6.562 ft	30 to 200 mm 1.181 to 7.874 in (Note 4)	5 to 160 mm 0.197 to 6.299 in (Note 5) with white non-glossy paper (200 × 200 mm) (7.874 × 7.874 in)	2 to 25 mm 0.079 to 0.984 in (Conv. point: 10 mm 0.394 in) with white non-glossy paper (50 × 50 mm) (1.969 × 1.969 in)	6 to 14 mm 0.236 to 0.551 in (Conv. point: 10 mm 0.394 in) with white non-glossy paper (50 × 50 mm) (1.969 × 1.969 in), spot diameter ø1 mm ø0.039 in with setting distance 10 mm 0.394 in	45 to 115 mm 1.772 to 4.528 in with white non-glossy paper (100 × 100 mm 3.937 × 3.937 in), spot diameter ø5 mm ø0.197 in with setting distance 80 mm 3.150 in
Sensing object			Min. ø2.6 mm ø0.102 in opaque object (Setting distance between emitter and receiver: 1 m 3.281 ft)	Min. ø3 mm ø0.118 in opaque object (Setting distance between emitter and receiver: 2 m 6.562 ft)	ø15 mm ø0.591 in or more opaque or translucent object (Note 4, 6)	Opaque, translucent or transparent object (Note 6)	Min. ø0.1 mm ø0.004 in copper wire (Setting distance: 10 mm 0.394 in)	Min. ø0.1 mm ø0.004 in copper wire (Setting distance: 10 mm 0.394 in)	Opaque, translucent or transparent object (Note 6) (Min. ø1 mm ø0.039 in copper wire at setting distance 80 mm 3.150 in)
Hysteresis			—————			15 % or less of operation distance [50 × 50 mm 1.969 × 1.969 in (EX-22□: 200 × 200 mm 7.874 × 7.874 in, EX-28□: 100 × 100 mm 3.937 × 3.937 in) (with white non-glossy paper)]			
Repeatability (perpendicular to sensing axis)			0.05 mm 0.002 in or less		0.5 mm 0.020 in or less	0.3 mm 0.012 in or less	0.1 mm 0.004 in or less (Setting distance: 10 mm 0.394 in)	0.05 mm 0.002 in or less (Setting distance: 10 mm 0.394 in)	0.3 mm 0.012 in or less
Supply voltage			12 to 24 V DC ±10 % Ripple P-P 10 % or less						
Current consumption			Emitter: 10 mA or less, Receiver: 10 mA or less		13 mA or less				15 mA or less
Output			<NPN output type> NPN open-collector transistor <ul style="list-style-type: none">Maximum sink current: 50 mAApplied voltage: 30 V DC or less (between output and 0 V)Residual voltage: 2 V or less (at 50 mA sink current) 1 V or less (at 16 mA sink current)				<PNP output type> PNP open-collector transistor <ul style="list-style-type: none">Maximum source current: 50 mAApplied voltage: 30 V DC or less (between output and +V)Residual voltage: 2 V or less (at 50 mA source current) 1 V or less (at 16 mA source current)		
			Utilization category			DC-12 or DC-13			
			Short-circuit protection			Incorporated			
Response time			0.5 ms or less						
Operation indicator			Orange LED (lights up when the output is ON) (thru-beam type: located on the receiver)						
Stability indicator			Green LED (lights up under stable light received condition or stable dark condition), located on the receiver		Green LED (lights up under stable light received condition or stable dark condition)				
Sensitivity adjuster			—————	Continuously variable adjuster, located on the emitter	Continuously variable adjuster		—————	Continuously variable adjuster	
Operation mode switch			—————	Located on the receiver		—————			
Environmental resistance	Pollution degree		3 (Industrial environment)						
	Protection		IP67 (IEC)						
	Ambient temperature		–25 to +55 °C –13 to +131 °F (No dew condensation or icing allowed), Storage: –30 to +70 °C –22 to +158 °F						
	Ambient humidity		35 to 85 % RH, Storage: 35 to 85 % RH						
	Ambient illuminance		Incandescent light: 3,000 lx or less at the light-receiving face						
	Voltage withstandability		1,000 V AC for one min. between all supply terminals connected together and enclosure						
	Insulation resistance		20 MΩ, or more, with 250 V DC megger between all supply terminals connected together and enclosure						
	Vibration resistance		10 to 500 Hz frequency, 3 mm 0.118 in double amplitude (20 G max.) in X, Y and Z directions for two hours each						
Shock resistance		500 m/s ² acceleration (50 G approx.) in X, Y and Z directions three times each							
Emitting element			Red LED (modulated)						
	Peak emission wavelength		640 nm 0.025 mil	650 nm 0.026 mil	680 nm 0.027 mil	680 nm 0.027 mil	680 nm 0.027 mil	650 nm 0.026 mil	650 nm 0.026 mil
Material			Enclosure: Polyarylate, Lens: Polyarylate						
Cable			0.1 mm ² 3-core (thru-beam type sensor emitter: 2-core) cabtyre cable, 2 m 6.562 ft long						
Cable extension			Extension up to total 50 m 164.042 ft is possible with 0.3 mm ² , or more, cable (thru-beam type: both emitter and receiver).						
Weight			Net weight (each emitter and receiver): 20 g approx. Gross weight: 60 g approx.		Net weight: 20 g approx., Gross weight: 45 g approx.				
Accessories			—————	Adjusting screwdriver: 1 pc.	RF-200 (Reflector): 1 pc. Adjusting screwdriver: 1 pc.	Adjusting screwdriver: 1 pc.	—————	Adjusting screwdriver: 1 pc.	

Notes: 1) Where measurement conditions have not been specified precisely, the conditions used were an ambient temperature of +23 °C +73.4 °F.

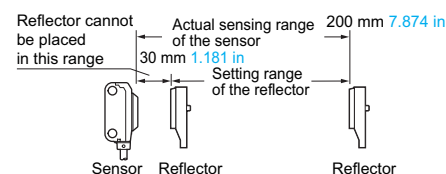
2) Model Nos. having the suffix "-PN" are PNP output type.

3) Either Light-ON or Dark-ON can be selected by the operation mode switch (located on the receiver).

4) The sensing range and the sensing object of the retroreflective type sensor are specified for the **RF-200** reflector. Further, the sensing range is the possible setting range for the reflector. The sensor can detect an object less than 30 mm 1.181 in away. However, if the reflector is set 100 mm 3.937 in or less away, the sensing object should be opaque.

5) In case of using this product at a sensing range of 50 mm 1.969 in or less, take care that the sensitivity adjustment range becomes extremely narrow.

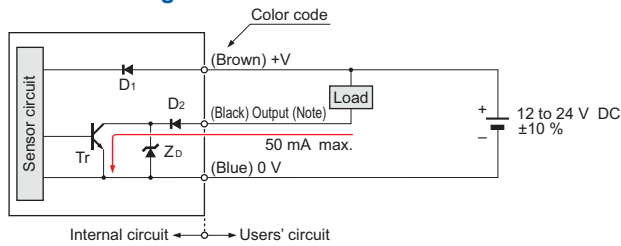
6) Make sure to confirm detection with an actual sensor before use.



I/O CIRCUIT AND WIRING DIAGRAMS

NPN output type

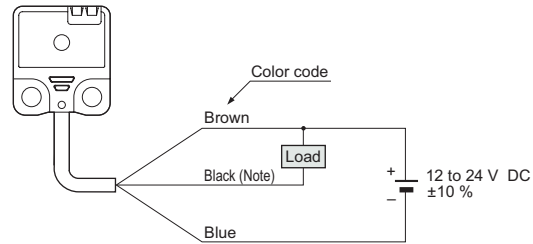
I/O circuit diagram



Note: The emitter of the thru-beam type sensor does not incorporate the output.

Symbols ... D1: Reverse supply polarity protection diode
D2: Reverse output polarity protection diode
ZD: Surge absorption zener diode
Tr: NPN output transistor

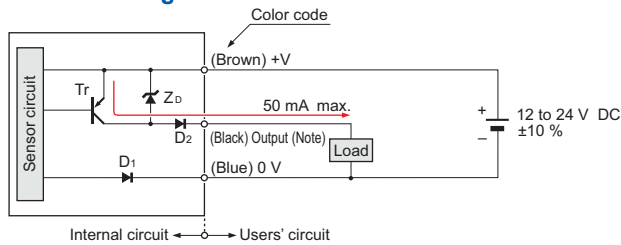
Wiring diagram



Note: The emitter of the thru-beam type sensor does not incorporate the black wire.

PNP output type

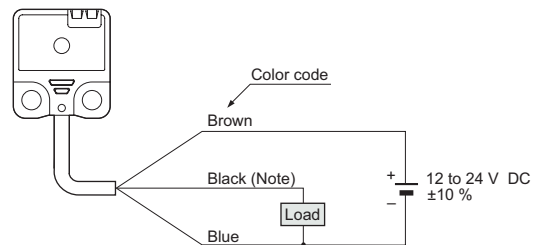
I/O circuit diagram



Note: The emitter of the thru-beam type sensor does not incorporate the output.

Symbols ... D1: Reverse supply polarity protection diode
D2: Reverse output polarity protection diode
ZD: Surge absorption zener diode
Tr: PNP output transistor

Wiring diagram

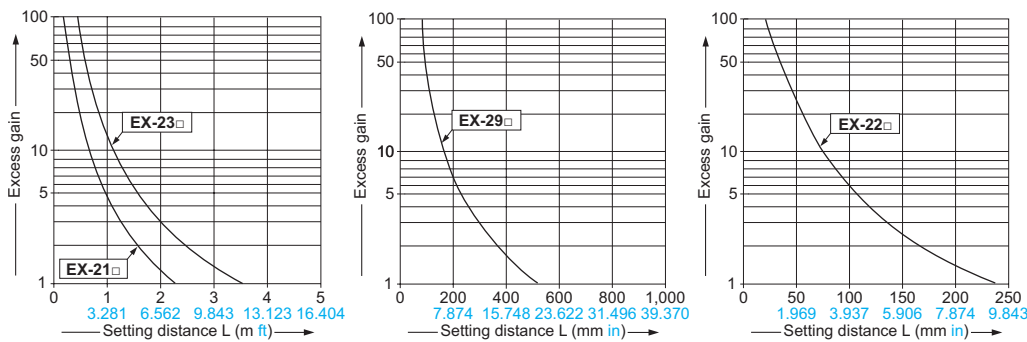


Note: The emitter of the thru-beam type sensor does not incorporate the black wire.

SENSING CHARACTERISTICS (TYPICAL)

EX-21 □ EX-23 □ EX-29 □ EX-22 □

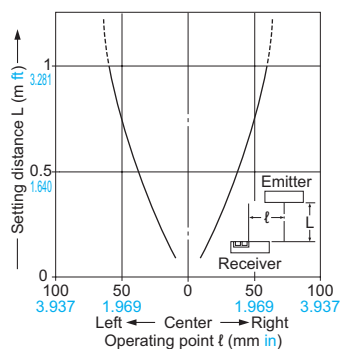
Correlation between setting distance and excess gain



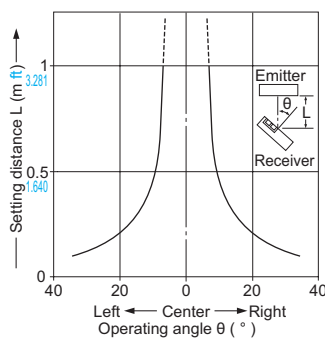
EX-21 □

Thru-beam type

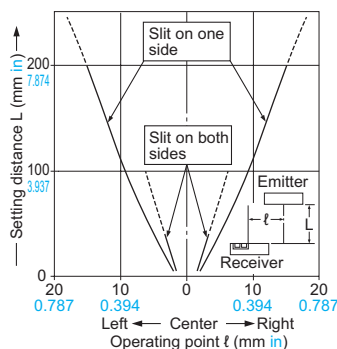
Parallel deviation



Angular deviation



Parallel deviation with round slit masks (ø0.5 mm ø0.020 in)



Parallel deviation with rectangular slit masks (0.5 × 3 mm 0.020 × 0.118 in)

